2SC3943

Silicon NPN epitaxial planar type

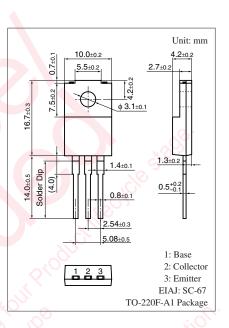
For video amplifier

Features

- High transition frequency f_T
- \bullet Small collector output capacitance (Common base, input open circuited) C_{ob}
- Full-pack package which can be installed to the heat sink with one screw

Absolute Maximum Ratings $T_a = 25^{\circ}C$

*			
Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	110	V
Collector-emitter voltage (Resistor between B and E)	V _{CER}	100	V
Collector-emitter voltage (Base open)	V _{CEO}	50	V
Emitter-base voltage (Collector open)	V _{EBO}	3.5	V
Collector current	I _C	150	mA
Peak collector current	I _{CP}	300	mA
Collector power dissipation *	P _C	2.0	W
Junction temperature	Tj	150	°C
Storage temperature	T _{stg}	-55 to +150	°C



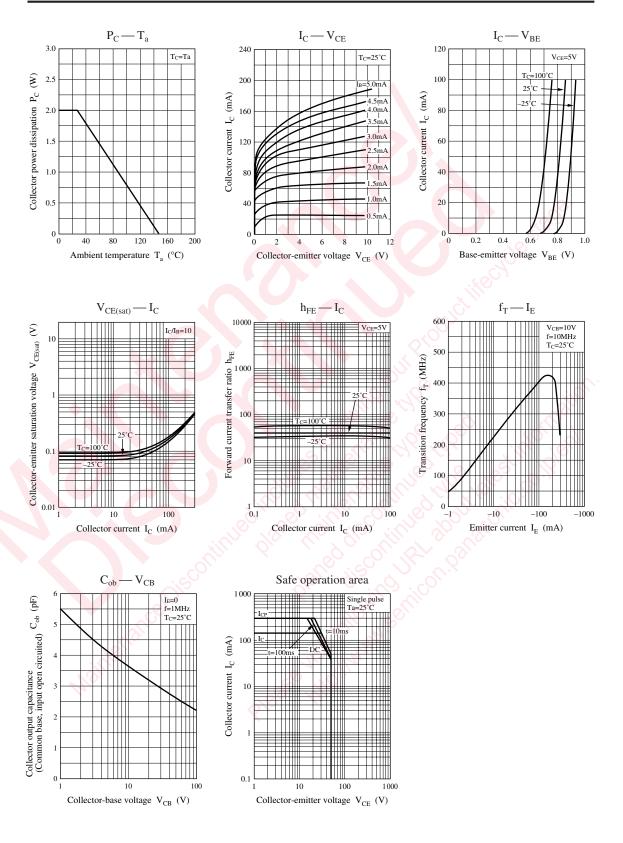
Note) *: Without heat sink

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = 100 \ \mu \text{A}, I_{\rm E} = 0$	110			V
Collector-emitter voltage (Resistor between B and E)	V _{CER}	$I_{\rm C} = 500 \ \mu {\rm A}, \ {\rm R}_{\rm BE} = 470 \ \Omega$	100			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 1 \text{ mA}, I_{\rm B} = 0$	50			V
Emitter-base voltage (Collector open)	V _{EBO}	$I_{\rm E} = 100 \ \mu A, I_{\rm C} = 0$	3.5			V
Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = 35 \text{ V}, I_{B} = 0$			10	μΑ
Forward current transfer ratio	h _{FE}	$V_{CE} = 5 V, I_C = 100 mA$	20			_
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = 150 \text{ mA}, I_{\rm B} = 15 \text{ mA}$			0.5	V
Transition frequency	f _{T1}	$V_{CB} = 10 \text{ V}, I_C = 10 \text{ mA}, f = 10 \text{ MHz}$		300		MHz
	f _{T2}	$V_{CB} = 10 \text{ V}, I_C = 110 \text{ mA}, f = 10 \text{ MHz}$		350		
Collector output capacitance (Common base, input open circuited)	C _{ob}	$V_{CB} = 30 V, I_E = 0, f = 1 MHz$		3.5		pF

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

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